

1. General description

Planar passivated very sensitive gate Silicon Controlled Rectifier in a SOT54 (TO-92) plastic package.

2. Features and benefits

- · Planar passivated for voltage ruggedness and reliability
- Very sensitive gate

3. Applications

- Ignition circuits
- Low power latching circuits
- Protection / shut-down circuits: lighting ballasts
- Protection / shut-down circuits: Switched Mode Power Supplies

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{RRM} | repetitive peak reverse voltage | | - | - | 400 | V |
| I _{T(AV)} | average on-state current | half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u> | - | - | 0.5 | A |
| I _{T(RMS)} | RMS on-state current | half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u> | - | - | 0.8 | A |
| I _{TSM} | non-repetitive peak on- state current | half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms | - | - | 9 | A |
| | | half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 8 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| Static chara | acteristics | · | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u> | - | - | 50 | μA |
| Dynamic ch | naracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 268 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12 | 500 | 800 | - | V/µs |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------|---|-----|-----|-----|------|
| | | V_{DM} = 268 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12 | - | 25 | - | V/µs |

5. Pinning information

| Table 2. F | Table 2. Pinning information | | | | | | | | |
|------------|------------------------------|-------------|--------------------|----------------|--|--|--|--|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol | | | | | |
| 1 | A | anode | | A - D- K | | | | | |
| 2 | G | gate | | G sym037 | | | | | |
| 3 | К | cathode | TO-92 (SOT54) | <i></i> | | | | | |

6. Ordering information

Table 3. Ordering information

| Type number Package | | | | | |
|---------------------|-------|---|---------|--|--|
| | Name | Description | Version | | |
| BT169D-L | TO-92 | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | |

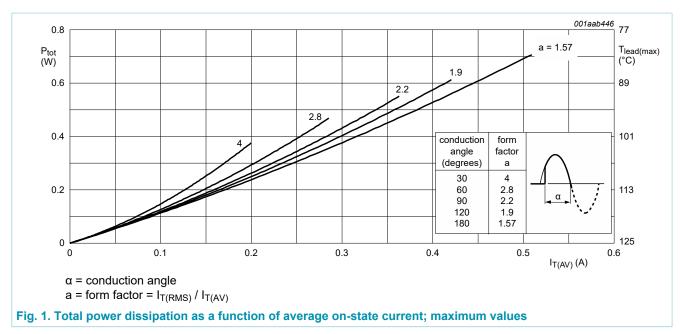
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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

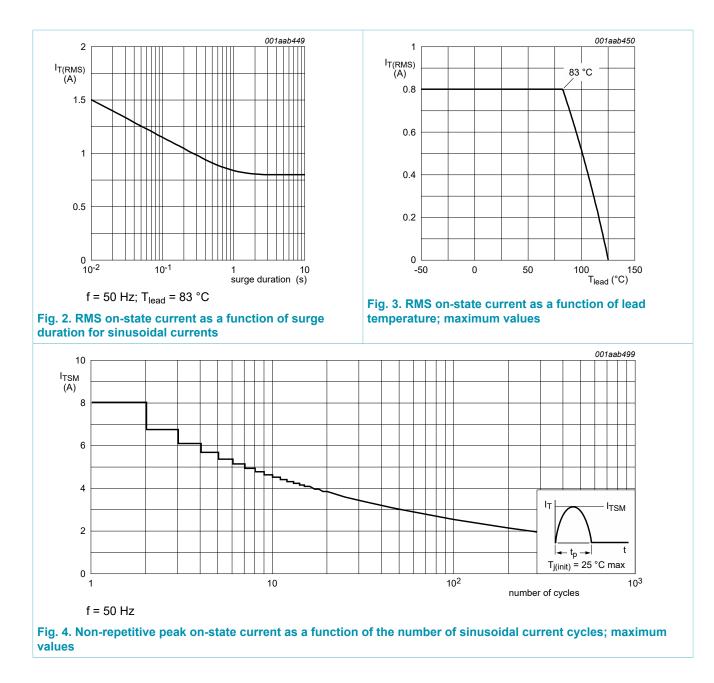
| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-----------------------------------|--|-----|------|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 400 | V |
| V _{RRM} | repetitive peak reverse voltage | | - | 400 | V |
| I _{T(AV)} | average on-state current | half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u> | - | 0.5 | А |
| I _{T(RMS)} | RMS on-state current | half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2; Fig. 3</u> | - | 0.8 | А |
| | non-repetitive peak on- | half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms | - | 9 | А |
| | state current | half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; Fig. 4; Fig. 5 | - | 8 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 0.32 | A²s |
| dl _T /dt | rate of rise of on-state current | $I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{dI}_G/\text{dt} = 100 \text{ mA}/\mu\text{s}$ | - | 50 | A/µs |
| I _{GM} | peak gate current | | - | 1 | А |
| V _{RGM} | peak reverse gate voltage | | - | 5 | V |
| P _{GM} | peak gate power | | - | 2 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.1 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |



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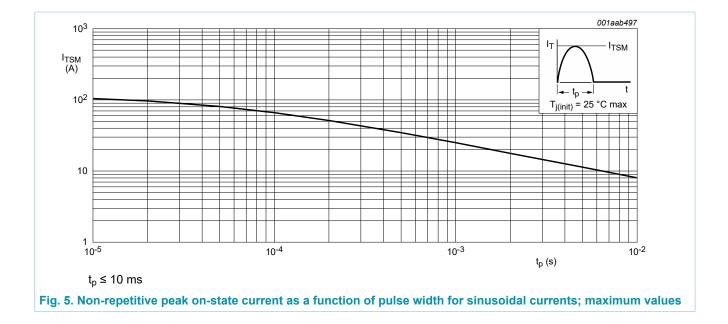
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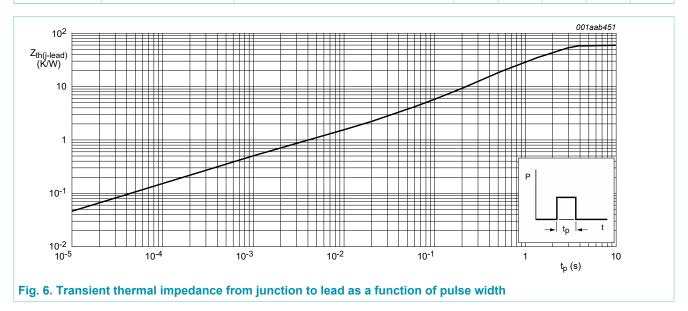


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8. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|--|-----|-----|-----|------|
| $R_{th(j-lead)}$ | thermal resistance from junction to lead | <u>Fig. 6</u> | - | - | 60 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient free air | printed circuit board mounted: lead length = 4 mm | - | 150 | - | K/W |

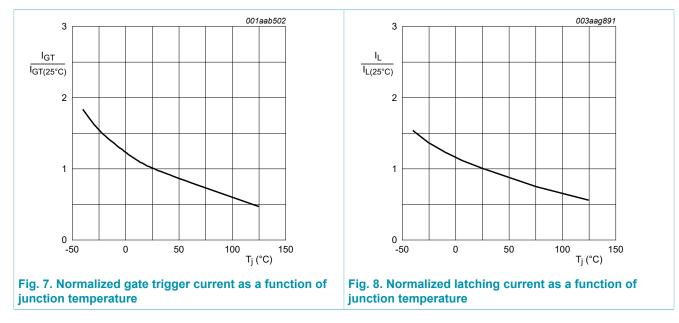


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9. Characteristics

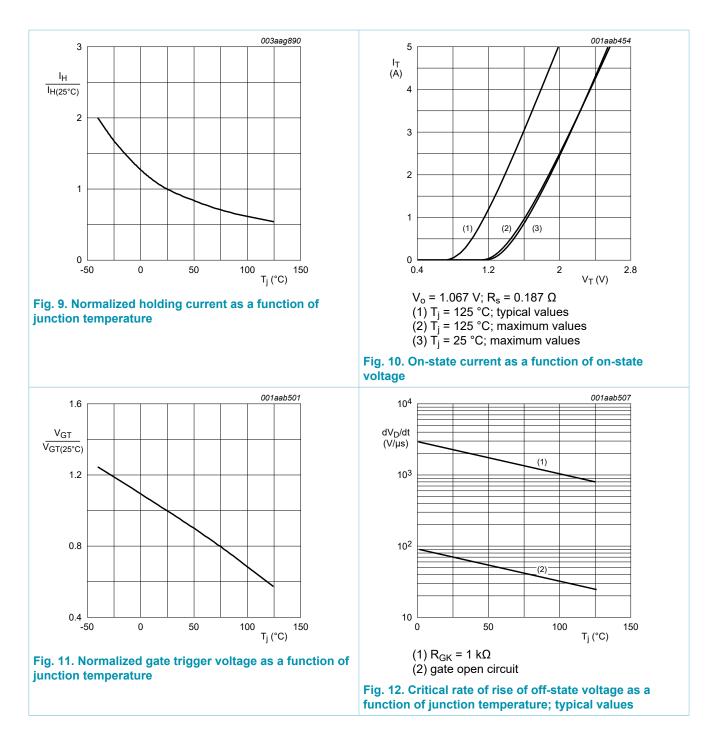
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|---|-----|------|-----|------|
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7 | - | - | 50 | μA |
| l | latching current | V _D = 12 V; I _G = 0.5 mA; T _j = 25 °C; Fig. 8 | - | 2 | 4 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 0.4 | 1 | mA |
| V _T | on-state voltage | I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.25 | 1.7 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 11</u> | - | 0.5 | 0.8 | V |
| | | V _D = 12 V; I _T = 10 mA; T _j = 125 °C; Fig. 11 | 0.2 | 0.3 | - | V |
| I _D | off-state current | V_D = 400 V; $R_{GK(ext)}$ = 1 kΩ; T_j = 25 °C | - | - | 2 | μA |
| | | V _D = 400 V; R _{GK(ext)} = 1 kΩ; T _j = 125 °C | - | 0.05 | 0.1 | mA |
| I _R | reverse current | V_{R} = 400 V; T _j = 25 °C; R _{GK(ext)} = 1 kΩ | - | 0.05 | 2 | μA |
| | | V_{R} = 400 V; T _j = 125 °C; R _{GK(ext)} = 1 kΩ | - | 0.05 | 0.1 | mA |
| Dynamic ch | aracteristics | · · · · | | | | |
| dV _D /dt | rate of rise of off-state voltage | $V_{DM} = 268 \text{ V}; \text{T}_{\text{j}} = 125 \text{ °C}; \text{R}_{\text{GK}} = 1 \text{ k}\Omega;$ (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12 | 500 | 800 | - | V/µs |
| | | V_{DM} = 268 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12 | - | 25 | - | V/µs |



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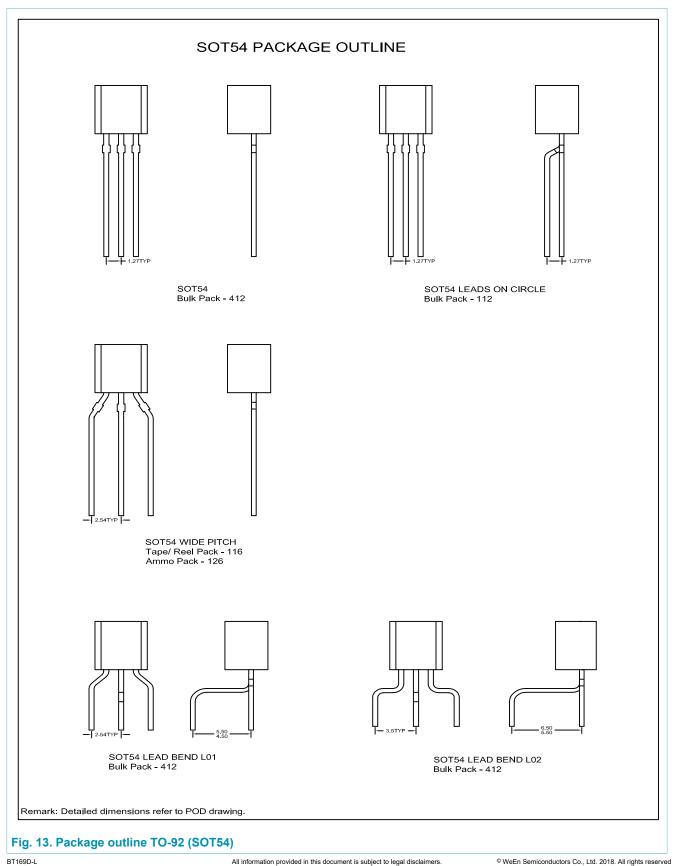
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10. Package outline



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11. Legal information

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|--------------------------------------|-------------------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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